

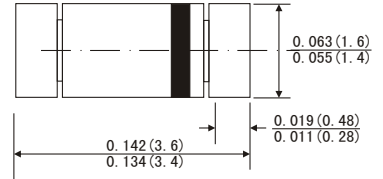
FEATURES

- For general purpose applications
- These diodes features very low turn-on voltage and fast switching.
- These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
- This diode is also available in the DO-35 case with the type designation BAT46.
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

MECHANICAL DATA

- Case: MiniMELF glass case(SOD-80)
- Weight: Approx. 0.05 gram

MiniMELF



Dimensions in inches and (millimeters)

ABSOLUTE RATINGS(LIMITING VALUES)

	Symbols	Value	Units
Repetitive Peak Reverse Voltage	V_{RRM}	100	V
Forward Continuous Current at $T_A=25^\circ\text{C}$	I_F	150 ¹⁾	mA
Repetitive Peak Forward Current at $t_p < 1\text{s}$, $\delta < 0.5$, $T_A=25^\circ\text{C}$	I_{FRM}	350 ¹⁾	mA
Surge forward current at $t_p < 10\text{ms}$, $T_A=25^\circ\text{C}$	I_{FSM}	750 ¹⁾	mA
Power Dissipation at $T_A=65^\circ\text{C}$	P_{tot}	150 ¹⁾	mW
Junction temperature	T_J	125	$^\circ\text{C}$
Ambient Operating temperature Range	T_A	-65 to +125	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +150	$^\circ\text{C}$

1) Valid provided that electrodes are kept at ambient temperature

ELECTRICAL CHARACTERISTICS

	Symbols	Min.	Typ.	Max.	Unis
Reverse Breakdown Voltage Tested with 100 μA Pulses	$V_{(BR)R}$	100			V
Forward Voltage Pulse Test $t_p < 300\mu\text{s}$, $V_R=10\text{V}$, $T_J=60^\circ\text{C}$, $\delta < 2\%$ at $I_F=0.1\text{mA}$, at $I_F=10\text{mA}$, at $I_F=250\text{mA}$	V_F V_F V_F			0.25 0.45 1	V V V
Leakage current pulse test $t_p < 300\mu\text{s}$, $\delta < 2\%$ at $V_R=1.5\text{V}$, at $V_R=1.5\text{V}$, $T_J=60^\circ\text{C}$ at $V_R=10\text{V}$, at $V_R=10\text{V}$, $T_J=60^\circ\text{C}$ at $V_R=50\text{V}$, at $V_R=50\text{V}$, $T_J=60^\circ\text{C}$ at $V_R=75\text{V}$, at $V_R=75\text{V}$, $T_J=60^\circ\text{C}$	I_R I_R I_R I_R I_R I_R I_R			0.5 5 0.8 7.5 2 15 5 20	μA μA μA μA μA μA μA μA
Junction Capacitance at $V_R=0\text{V}$, $f=1\text{MHz}$ at $V_R=1\text{V}$, $f=1\text{MHz}$	C_J C_J		10 6		pF pF
Thermal resistance junction to ambient Air	$R_{\theta JA}$			300 ¹⁾	K/W

1) Valid provided that electrodes are kept at ambient temperature

RATINGS AND CHARACTERISTIC CURVES LL46

Figure 1. Forward current versus forward voltage at different temperatures (typical values)

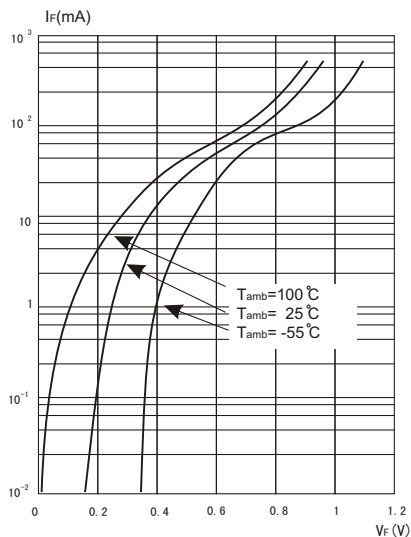


Figure 2. Forward current versus forward voltage (typical values)

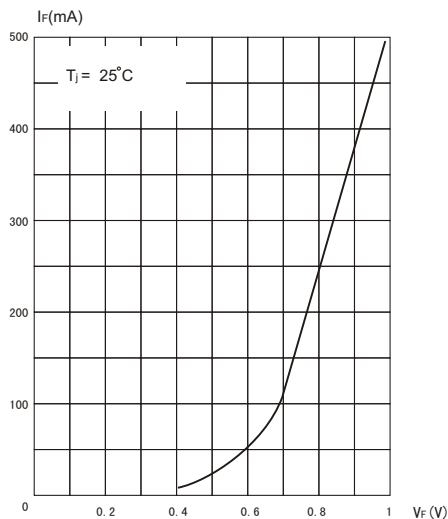
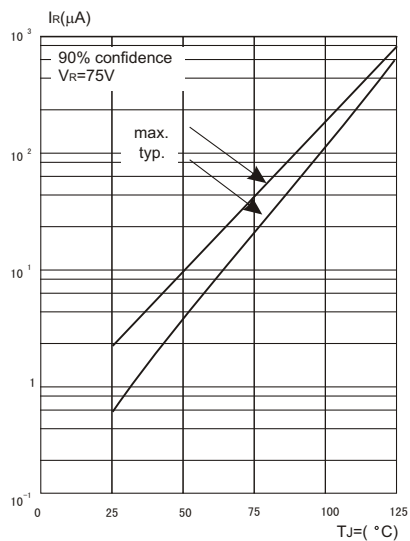


Figure 3. Reverse current versus junction temperature (typical values)



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Figure 4. Reverse current versus continuous Reverse voltage

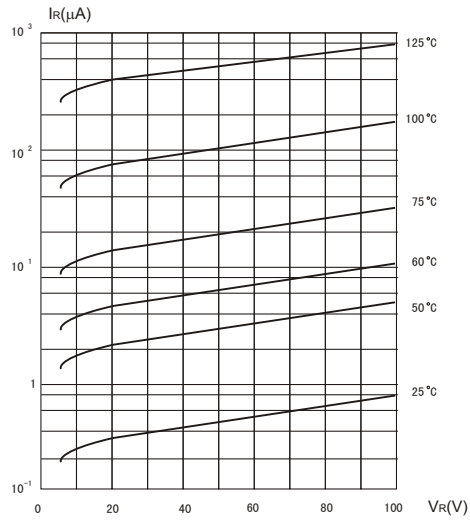


Figure 5. Capacitance C_J versus reverse applied voltage V_R (typical values)

